

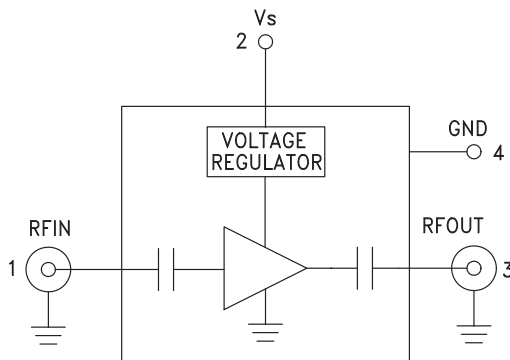


### Typical Applications

The HMC-C001 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

### Functional Diagram



### Features

Noise Figure: 2 dB @ 10 GHz

Flat Gain: 15 dB ± 0.5 dB

P1dB Output Power: +14 dBm @ 10 GHz

50 Ohm Matched Input/Output

Regulated Supply + 9V to +15V @ 65mA

Hermetically Sealed Module

Field Replaceable SMA connectors

-55 to +85°C Operating Temperature

### General Description

The HMC-C001 is a GaAs MMIC PHEMT Low Noise Distributed Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 2 and 20 GHz. The self-biased amplifier provides 15 dB of gain, 2 to 3 dB noise figure and +14 dBm of output power at 1 dB gain compression while requiring a single +12V supply. Gain flatness is excellent from 2 - 18 GHz making the HMC-C001 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are internally DC blocked.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , $V_s = +9\text{V to } +15\text{V}$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	2.0 - 6.0			6.0 - 16.0			16.0 - 20.0			GHz
Gain	13	15		12	14.5		11	13		dB
Gain Flatness		±0.25			±0.5			±0.5		dB
Gain Variation Over Temperature		0.015	0.025		0.015	0.025		0.015	0.025	dB/°C
Noise Figure		3.5	4.5		2.5	3.5		4.0	5.0	dB
Input Return Loss		15			20			10		dB
Output Return Loss		13			15			8		dB
Output Power for 1 dB Compression (P1dB)	11	14		10	13		8.5	11.5		dBm
Saturated Output Power (P <sub>sat</sub> )		17			15.5			14		dBm
Output Third Order Intercept (IP3)		25			23			21		dBm
Supply Current		78			78			78		mA

# HMC-C001\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

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## COMPARABLE PARTS

View a parametric search of comparable parts.

## DOCUMENTATION

### Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers

### Data Sheet

- HMC-C001 Data Sheet

## TOOLS AND SIMULATIONS

- HMC-C001 S-Parameter

## DESIGN RESOURCES

- HMC-C001 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all HMC-C001 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK

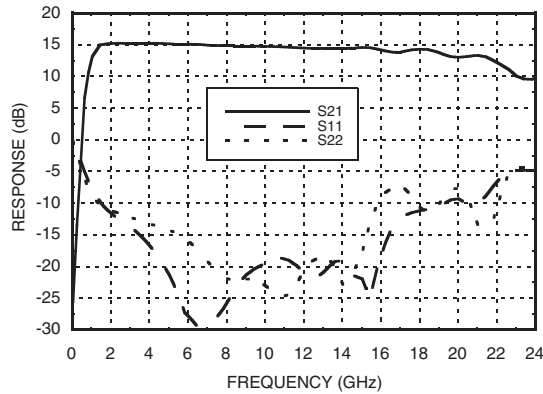
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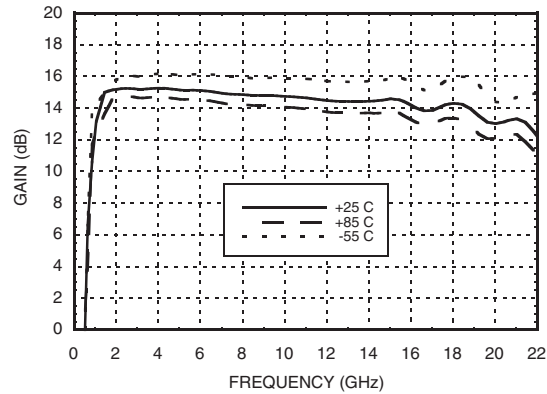


**WIDEBAND LNA MODULE, 2 - 20 GHz**

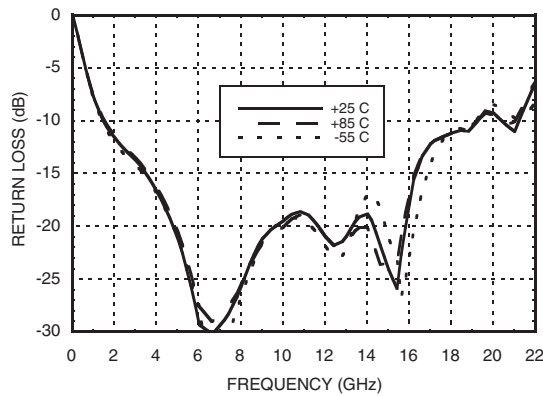
**Gain & Return Loss**



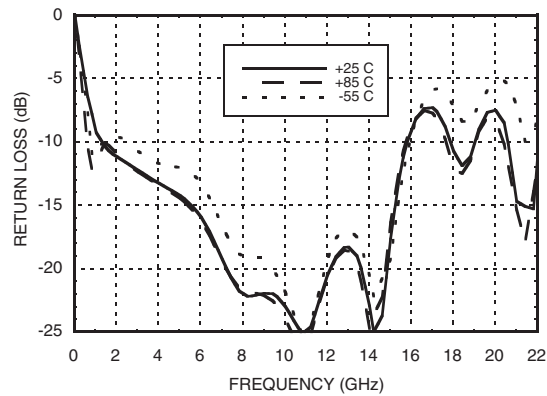
**Gain vs. Temperature**



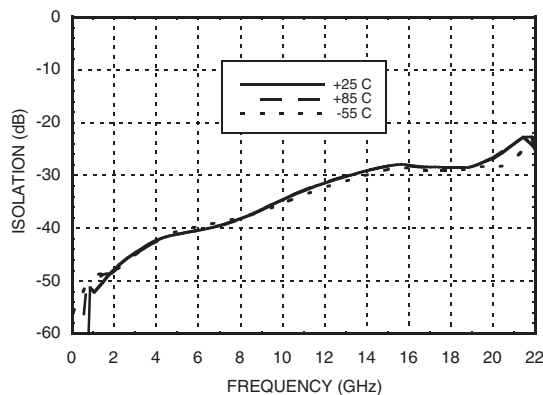
**Input Return Loss vs. Temperature**



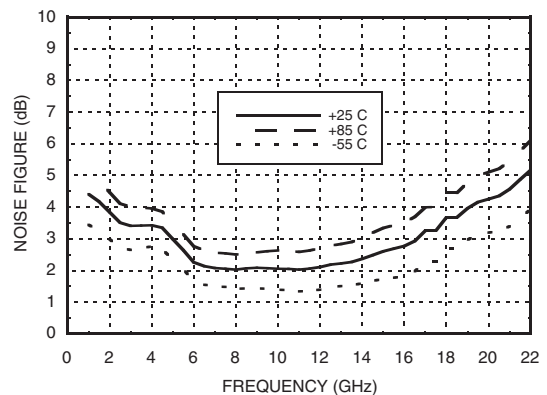
**Output Return Loss vs. Temperature**



**Reverse Isolation vs. Temperature**



**Noise Figure vs. Temperature**



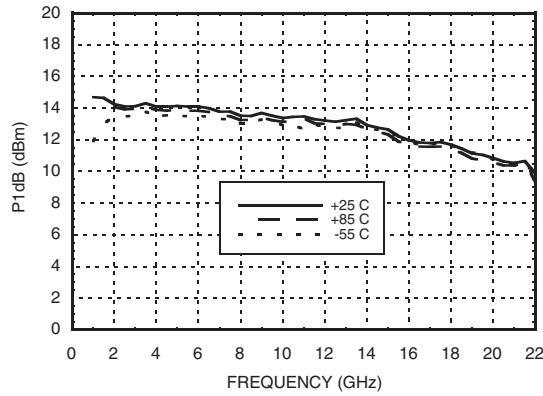
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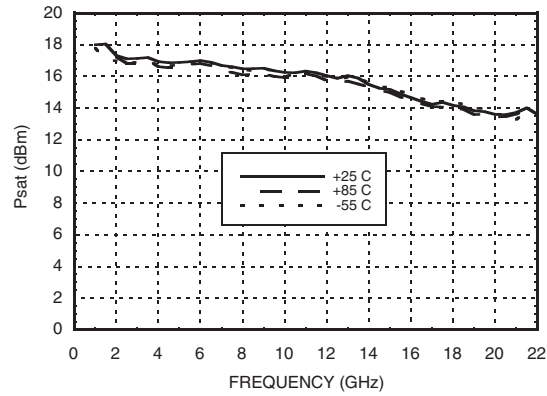
**WIDEBAND LNA MODULE, 2 - 20 GHz**



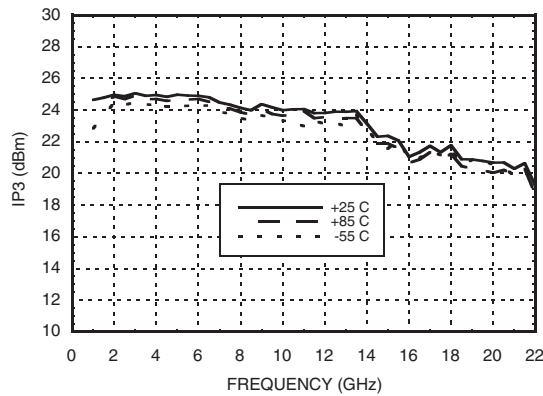
**P1dB vs. Temperature**



**Psat vs. Temperature**



**Output IP3 vs. Temperature**



**Absolute Maximum Ratings**

Bias Supply Voltage (Vs)	-0.3 Vdc to +25 Vdc
RF Input Power (RFIN)	+23 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

**Pin Descriptions**

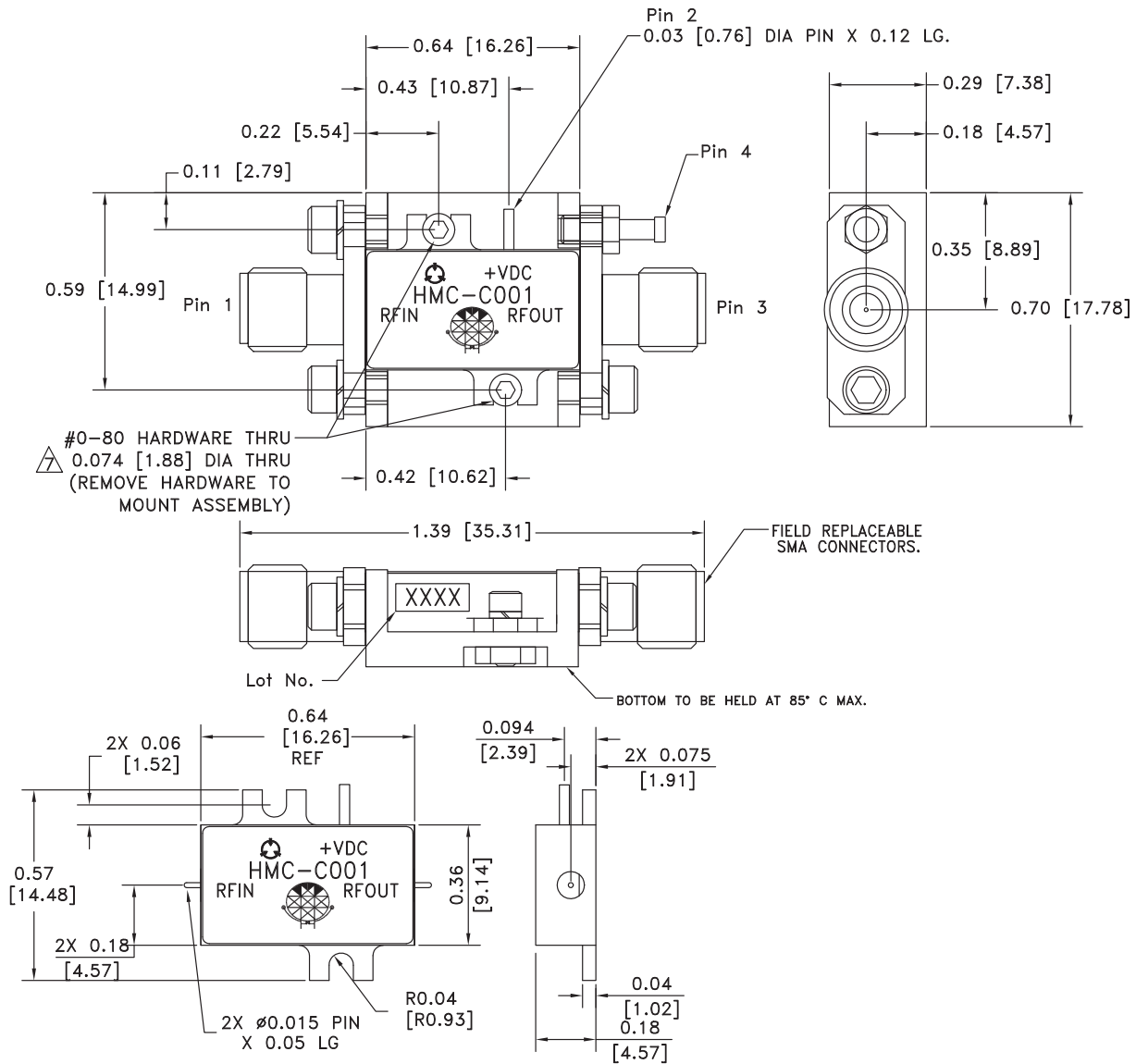
Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
2	Vs	Power supply voltage for the amplifier.	
3	RFOUT & RF Ground	RF output connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
4	GND	Power supply ground.	

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**Outline Drawing**



**Package Information**

Package Type	C-1
Package Weight [1]	10.2 gms [2]
Spacer Weight	N/A

[1] Includes the connectors

[2] ±1 gms Tolerance

**NOTES:**

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
  2. BRACKET MATERIAL: ALUMINUM
  3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
  4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
  5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
  6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602 - 5CCSF OR EQUIVALENT.
- △ TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 - 80 HARDWARE WITH DESIRED MOUNTING SCREWS.